



DMP4015SPSQ

40V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	RDS(ON) Max	ID Ta = +25°C
-40V	11mΩ @ V _{GS} = -10V	-11A
-40 V	15mΩ @ V _{GS} = -4.5V	-10A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC converters
- Power management functions
- Analog switches

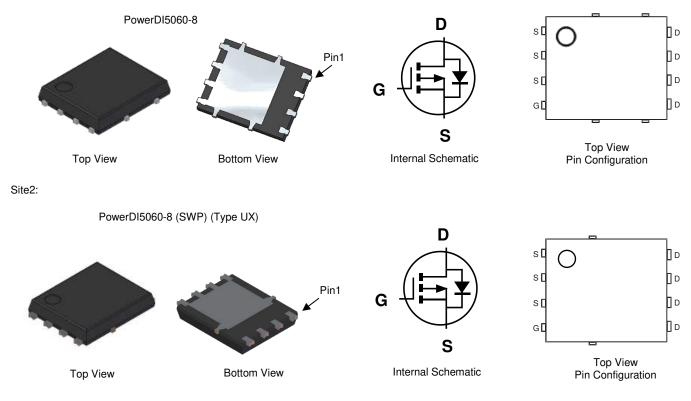
Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMP4015SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—100% Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (2)
- Weight: 0.097 grams (Approximate)



PowerDI is a registered trademark of Diodes Incorporated.

Site1:



Ordering Information (Note 4)

Part Number	Bookogo	Packing		
Fait Number	Part Number Package -		Carrier	
DMP4015SPSQ-13	PowerDI5060-8	2,500	Reel	
DMP4015SPSQ-13	PowerDI5060-8 (SWP) (Type UX)	2,500	Reel	

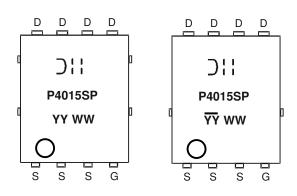
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



Difference Marking P4015SP = Product Type Marking Code YYWW or YYWW = Date Code Marking YY or YY = Year (ex: 22 = 2022) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value -40	Unit V		
Drain-Source Voltage	V _{DSS}				
Gate-Source Voltage	Vgss	±25	V		
	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-8.5 -6.8	А
Continuous Drain Current (Note 5) $V_{GS} = -10V$	t < 10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-13.0 -10.5	А
Continuous Drain Current (Note 6) V _{GS} = -10V	Steady State	TA = +25°C TA = +70°C	ID	-11.0 -8.7	A
	t < 10s	TA = +25°C TA = +70°C	ID	-17.0 -13.5	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	-100	А
Maximum Body Diode Continuous Current (Note 6)			ls	-11	А
Avalanche Current L = 1mH			las	-22	А
Avalanche Energy L = 1mH			Eas	242	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Tetal Dawar Dissinction (Nata 5)	TA = +25°C	D-	1.3	W
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	PD	0.8	
Thermal Resistance. Junction to Ambient (Note 5)	Steady State	Reja	96.4	°C/W
mermai Resistance, Junction to Ambient (Note 5)	t < 10s		40.6	°C/W
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	PD	2.1	W
Total Fower Dissipation (Note 6)	$T_A = +70^{\circ}C$		1.4	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	ReJA	49	°C/W
mermai Resistance, Junction to Ambient (Note 6)	t < 10s	ПθJA	24	°C/W
Thermal Resistance, Junction to Case (Note 7)		R _{eJC}	1.6	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1 inch square copper plate.

7. Thermal resistance from junction to soldering point (on the exposed drain pad).



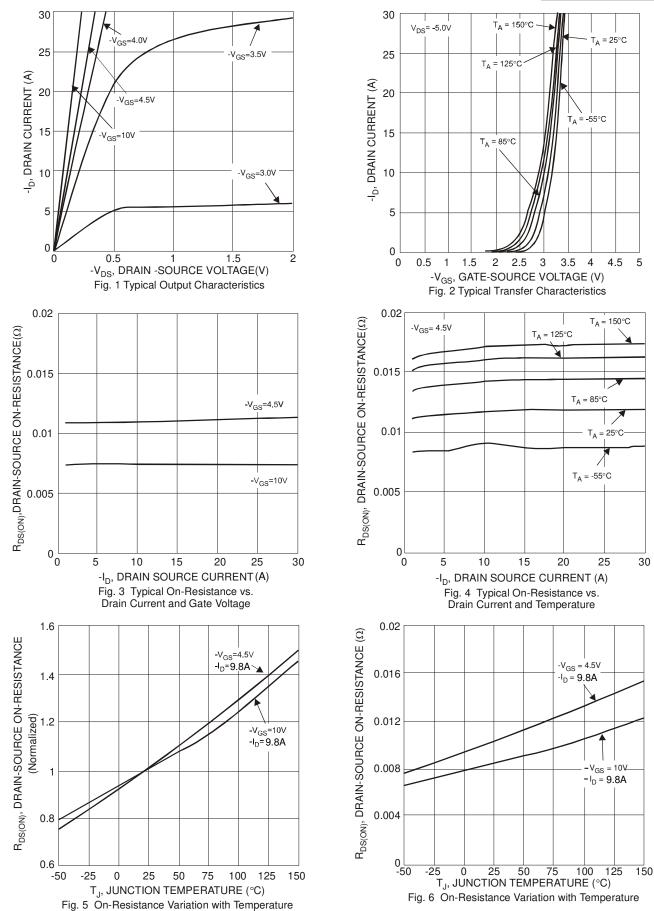
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BVDSS	-40	—	_	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	—	—	-1	μΑ	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	—	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	VGS(TH)	-1.5	-2	-2.5	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Descent	_	7	11	mΩ	V _{GS} = -10V, I _D = -9.8A	
Static Drain-Source On-Resistance	RDS(ON)	_	9	15	11122	$V_{GS} = -4.5V, I_{D} = -9.8A$	
Forward Transfer Admittance	Y _{fs}		26	—	S	$V_{DS} = -20V, I_D = -9.8A$	
Diode Forward Voltage	Vsd	_	-0.7	-1	V	VGS = 0V, IS = -1A	
DYNAMIC CHARACTERISTICS (Note 9)						·	
Input Capacitance	Ciss	_	4,234	_		$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	1,036	—	pF		
Reverse Transfer Capacitance	Crss	_	526	_			
Gate Resistance	Rg		7.77	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	47.5	_			
Gate-Source Charge	Qgs		14.2	—	nC	$V_{DS} = -20V, V_{GS} = -5V$	
Gate-Drain Charge	Qgd	_	13.5	_		ID = -9.8A	
Turn-On Delay Time	t _{D(ON)}	_	13.2	—	-	$V_{GS} = -10V, V_{DD} = -20V, R_G = 6\Omega,$ $I_D = -1A, R_L = 20\Omega$	
Turn-On Rise Time	tR	_	10	—			
Turn-Off Delay Time	tD(OFF)	_	302.7	_	ns		
Turn-Off Fall Time	tF		137.9	_			

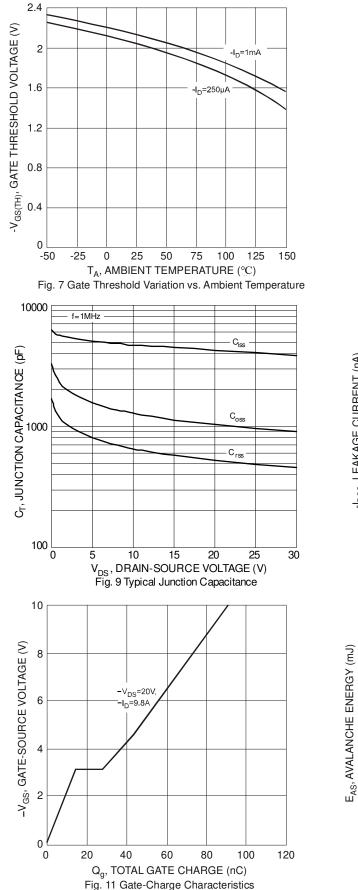
Notes: 8. Short duration pulse test used to minimize self-heating effect 9. Guaranteed by design. Not subject to production testing.

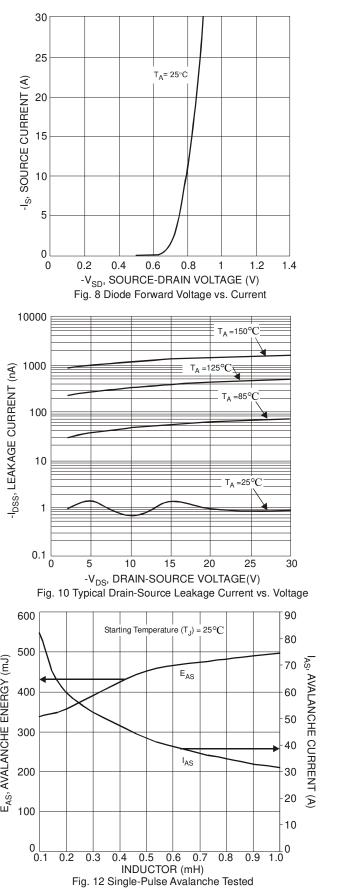




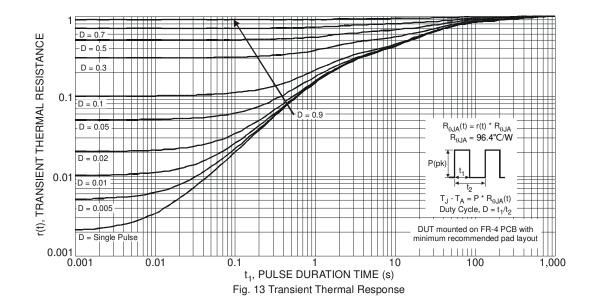










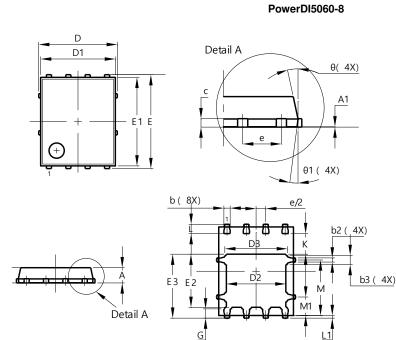




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

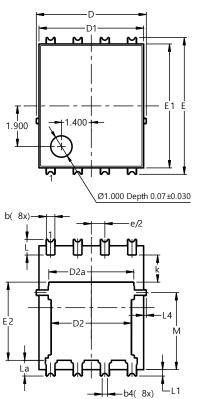
Site1:

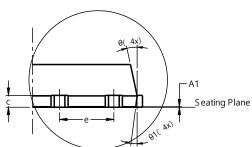


	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E		6.15 BSC			
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
e G		1.27 BSC			
G	0.51	0.71	0.61		
К	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
Al	All Dimensions in mm				

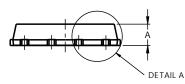
Site2:

PowerDI5060-8 (SWP) (Type UX)





DETAIL A



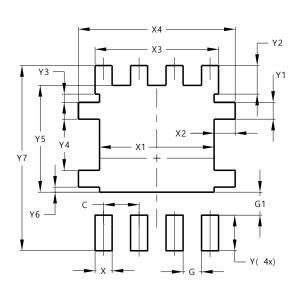
PowerDI5060-8 (SWP) (Type UX)			
Dim	Min	Max	Тур
Α	0.90	1.10	1.00
A1	0	0.05	
b	0.30	0.50	0.41
b2	0.20	0.35	0.25
b4	().25REF	-
С	0.230	0.330	0.277
D	5	.15 BS0	2
D1	4.70	5.10	4.90
D2	3.56	3.96	3.76
D2a	3.78	4.18	3.98
Е	6	6.40 BSC	2
E1	5.60	6.00	5.80
E2	3.46	3.86	3.66
E2a	4.195	4.595	4.395
е	1	.27BSC)
k	1.05		
L	0.635	0.835	0.735
La	0.635	0.835	0.735
L1	0.200	0.400	0.300
L1a	-	.050RE	-
L4	0.025	0.225	0.125
М	3.205	4.005	3.605
θ	10°	12°	11°
θ1	6°	8°	7°
All Dimensions in mm			



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site1:

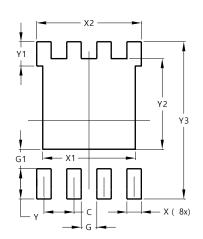


Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
¥7	6.610

Site2:

PowerDI5060-8 (SWP) (Type UX)

PowerDI5060-8



Dimensions	Value (in mm)	
С	1.270	
G	0.660	
G1	0.820	
Х	0.610	
X1	4.100	
X2	4.420	
Y	1.270	
Y1	1.020	
Y2	3.810	
Y3	6.610	



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